IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Madan et al.

Docket No.: TI-34844

Serial No.:

TBD

Examiner:

TBD

Filed:

Herewith

Art Unit:

TBD

For:

CIRCUIT AND METHOD FOR REDUCING ACCESS TRANSISTOR

GATE OXIDE STRESS

INFORMATION DISCLOSURE STATEMENT

July 2, 2003

Assistant Commissioner for Patents Washington, DC 20231

I hereby certify that this correspondence is being deposited with the United States Postal Service in an envelope addressed to: Assistant Commissioner for Patents, Washington, DC 20231, on July 2, 2003.

MAILING CERTIFICATE UNDER 37 C.F.R. § 1.8(A)

Robert N. Rountree, Reg. No. 39,347

Dear Sir:

Applicant wishes to bring to the attention of the Patent and Trademark Office the information noted on the enclosed PTO-1449. Copies of the listed references are enclosed.

This information disclosure statement is being mailed before receipt of a first office action on the merits in accordance with 37 C.F.R. 1.97(b)(3).

Respectfully submitted,

Robert N. Rountree Attorney for Applicants

Reg. No. 39,347

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* .	Approved for use through	10/31/2002	OMB 0651-0031

Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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STATEMENT BY APPLICANT				First Named Inventor	Madan		
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Sheet	1	of	2	Attorney Docket No.	TI-34844		

U.S. PATENT DOCUMENTS									
Exam. Initials	Cite No.1	U.S. Patent Document		Name of Patentee or	Date of Pub. of				
		Number	Kind Code ² (if known)	Applicant of Cited Doc.	Cited Doc. (mm- dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear			
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¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

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STATEMENT DI AFFEICANT				Group Art Unit	TBD		
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Sheet	2	of	2	Attorney Docket No.	TI-34844		

		OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS						
Exam. Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.						
	CA	ALI SHEIKHOLESLAMI et al., A Survey of Circuit innovations in Ferroelectric Random-Access Memories, Proc. of the IEEE, Vol. 88, No. 5, 667 (May 2000).						
	СВ	ALI SHEIKHOLESLAMI, Ferroelectric Memory Design (FeRAM 101), ISSCC 2002 Tutorial (February 3, 2002).						
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